NSN 5962-00-584-1646

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View Online at https://aerobasegroup.com/nsn/5962-00-584-1646 **Body Length:** Between 0.665 inches and 0.785 inches **Body Width:** Between 0.220 inches and 0.280 inches **Body Height:** Between 0.140 inches and 0.180 inches **Maximum Power Dissipation Rating:** 500.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Type an/tcc-78 multiplexer set **Features Provided:** Monolithic and hermetically sealed and low power and high gain and negative outputs and positive outputs **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Input Circuit Pattern:** Dual 2 input **Case Outline Source And Designator:** T0-116 joint electron device engineering council **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 15.0 volts power source **Time Rating Per Chacteristic:** 800.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 80063-sm-a-732441 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 15 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

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